

# **HD74HC679**

## 12-bit Address Comparator

REJ03D0640-0200 (Previous ADE-205-526) Rev.2.00 Mar 30, 2006

#### **Description**

The HD74HC679 address comparator simplifies addressing of memory boards and/or other peripheral devices. The four P inputs are normally hard wired with a preprogrammed address. An internal decoder determines what input information applied to the 12 A inputs must be low or high to cause a low state at the output (Y). For example, a positive-logic bit combination of 0111 (decimal 7) at the P input determines that inputs  $A_1$  through  $A_7$  must be low and that inputs  $A_8$  through  $A_{12}$  must be high to cause the output to go low. Equality of the address amplified at the A inputs to the preprogrammed address is indicated by the output being low.

The HD74HC679 features and enable input  $(\overline{G})$ . When  $\overline{G}$  is low, the device is enabled. When  $\overline{G}$  is high, the device is disabled and the output is high regardless of the A and P inputs.

#### **Features**

• High Speed Operation:  $t_{pd}$  (A to Y) = 18 ns typ ( $C_L = 50 \text{ pF}$ )

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$ 

• Low Input Current: 1 µA max

• Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max (Ta = 25°C)

• Ordering Information

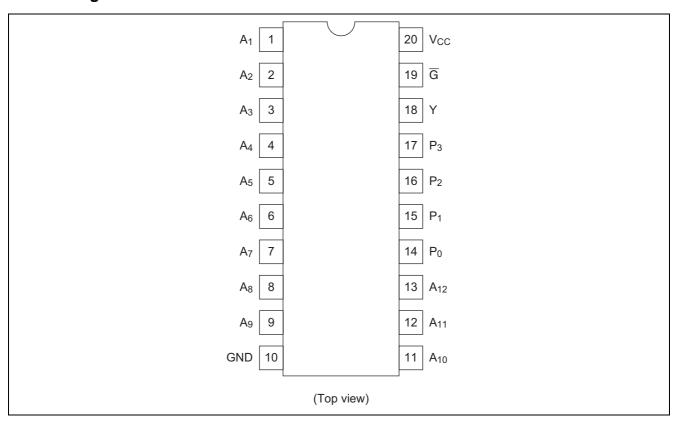
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC679RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

## **Function Table**

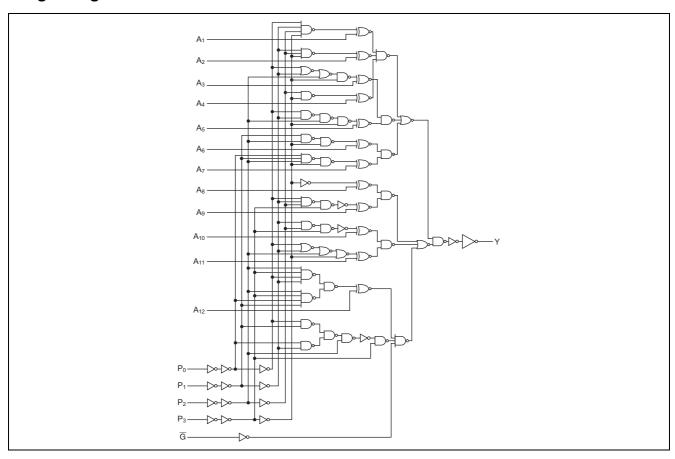
	Inputs																
G	P <sub>3</sub>	P <sub>2</sub>	P <sub>1</sub>	P <sub>0</sub>	<b>A</b> <sub>1</sub>	A <sub>2</sub>	$A_3$	$A_4$	$A_5$	$A_6$	<b>A</b> <sub>7</sub>	A <sub>8</sub>	A <sub>9</sub>	A <sub>10</sub>	A <sub>11</sub>	A <sub>12</sub>	Output Y
L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	L	Н	L	L	L	Н	Н	Ι	Ι	Н	Н	Ι	Н	Н	Н	L
L	L	L	Н	Н	L	L	L	Н	Ι	Ι	Н	Н	Ι	Н	Н	Н	L
L	L	Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	L
L	L	Н	L	Н	L	L	L	L	L	Ι	Н	Н	Ι	Н	Н	Н	L
L	L	Н	Н	L	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	L
L	L	Н	Н	Н	L	L	L	L	L	L	L	Н	Н	Н	Н	Н	L
L	Н	L	L	L	L	L	L	L	L	L	L	L	Н	Н	Н	Н	L
L	Н	L	L	Н	L	L	L	L	L	L	L	L	L	Н	Н	Н	L
L	Н	L	Н	L	L	L	L	L	L	L	L	L	L	L	Н	Н	L
L	Н	L	Н	Н	L	L	L	L	L	L	L	L	L	L	L	Н	L
L	Ι	Н	L	L	L	L	L	L	L	L	L	L	L	L	L	L	L
L	Н	Н	L	Н	Χ	Χ	Х	Χ	Χ	Χ	Х	Х	Χ	Х	Х	Х	Н
L	Н	Н	Н	L	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Н
L	H H H H L L L L L L L L L L L L									L							
L	L All other combinations							Н									
Н	Any combination								Н								

H: high levelL: low levelX: irrelevant

## **Pin Arrangement**



## **Logic Diagram**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> +0.5	V
Input / Output diode current	I <sub>IK</sub> , I <sub>OK</sub>	±20	mA
Output current	I <sub>OUT</sub>	±25	mA
V <sub>CC</sub> , GND current	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA
Power dissipation	P <sub>T</sub>	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

## **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions	
Supply voltage	V <sub>CC</sub>	2 to 6	V		
Input / Output voltage	V <sub>IN</sub> , V <sub>OUT</sub>	0 to V <sub>CC</sub>	V		
Operating temperature	Та	-40 to 85	°C		
		0 to 1000		V <sub>CC</sub> = 2.0 V	
Input rise / fall time*1	t <sub>r</sub> , t <sub>f</sub>	0 to 500	ns	V <sub>CC</sub> = 4.5 V	
		0 to 400		$V_{CC} = 6.0 \text{ V}$	

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

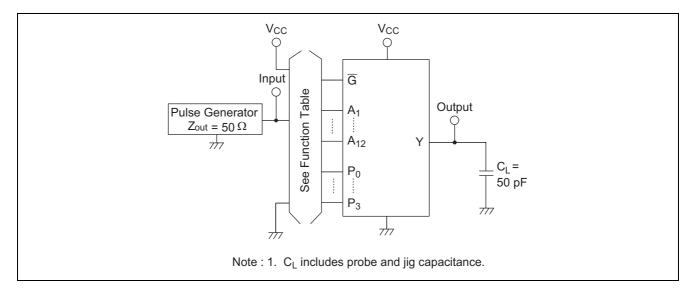
## **Electrical Characteristics**

			Т	a = 25°	С	Ta = -40 to+85°C			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Input voltage	$V_{IH}$	2.0	1.5	_	_	1.5	_	V	
		4.5	3.15	_	_	3.15	_		
		6.0	4.2	_	_	4.2	_		
	$V_{IL}$	2.0	_	_	0.5	_	0.5	V	
		4.5		-	1.35	_	1.35		
		6.0	_	_	1.8	_	1.8		
Output voltage	$V_{OH}$	2.0	1.9	2.0	_	1.9	_	V	Vin = $V_{IH}$ or $V_{IL}$ $I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_		
		6.0	5.9	6.0	_	5.9	_		
		4.5	4.18	_	_	4.13	_		$I_{OH} = -4 \text{ mA}$
		6.0	5.68	_	_	5.63	_		$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL} \mid I_{OL} = 20 \mu A$
		4.5	_	0.0	0.1	_	0.1		
		6.0	_	0.0	0.1	_	0.1		
		4.5	_	_	0.26	_	0.33		$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	_	0.33		$I_{OL} = 5.2 \text{ mA}$
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GND
Quiescent supply current	Icc	6.0	_	_	4.0	_	40	μА	Vin = $V_{CC}$ or GND, lout = $0 \mu A$

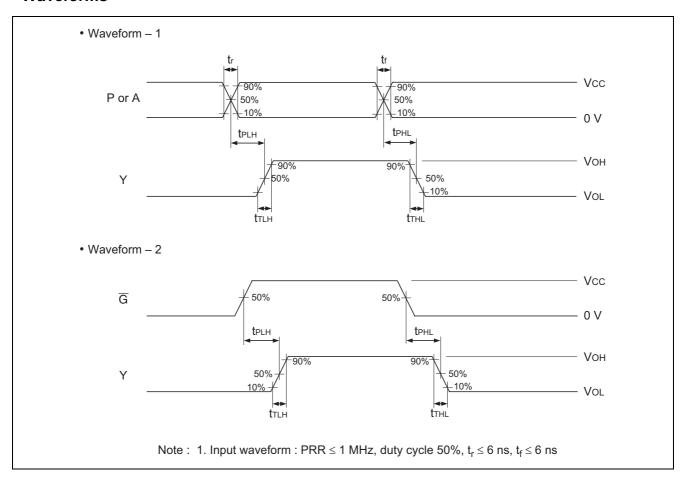
# Switching Characteristics ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

			Т	a = 25°	С	Ta = -40 to +85°C			
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	_	310	_	390	ns	P to Y
time	t <sub>PHL</sub>	4.5	_	27	62	_	78		
		6.0	_	_	52	_	66		
	t <sub>PLH</sub>	2.0	_	_	180	_	225	ns	A to Y
	t <sub>PHL</sub>	4.5	_	18	36	_	45		
		6.0	_	_	31	_	38		
	t <sub>PLH</sub>	2.0	_	_	125	_	155	ns	G to Y
	t <sub>PHL</sub>	4.5	_	14	25	_	31		
		6.0	_	_	21	_	26		
Output rise/fall	t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
time	t <sub>THL</sub>	4.5	_	5	15	_	19		
		6.0	_	_	13	_	16		
Input capacitance	Cin	_	_	5	10	_	10	pF	

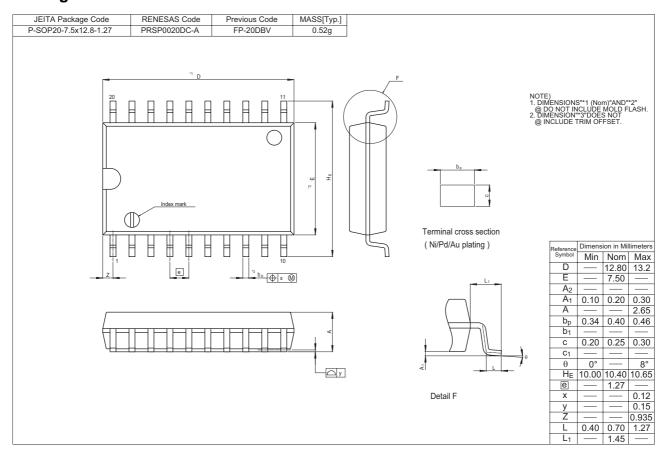
#### **Test Circuit**



## **Waveforms**



## **Package Dimensions**



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